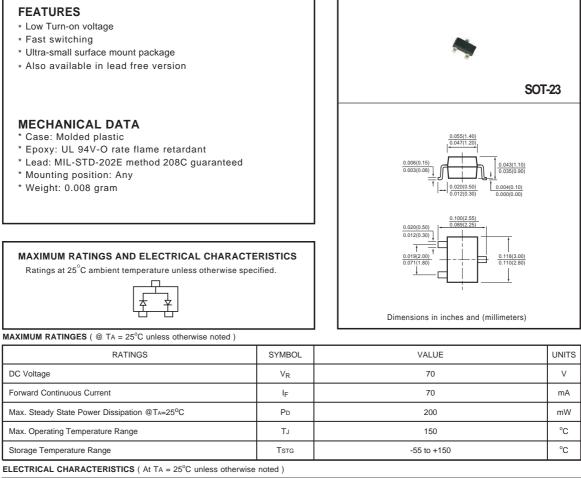




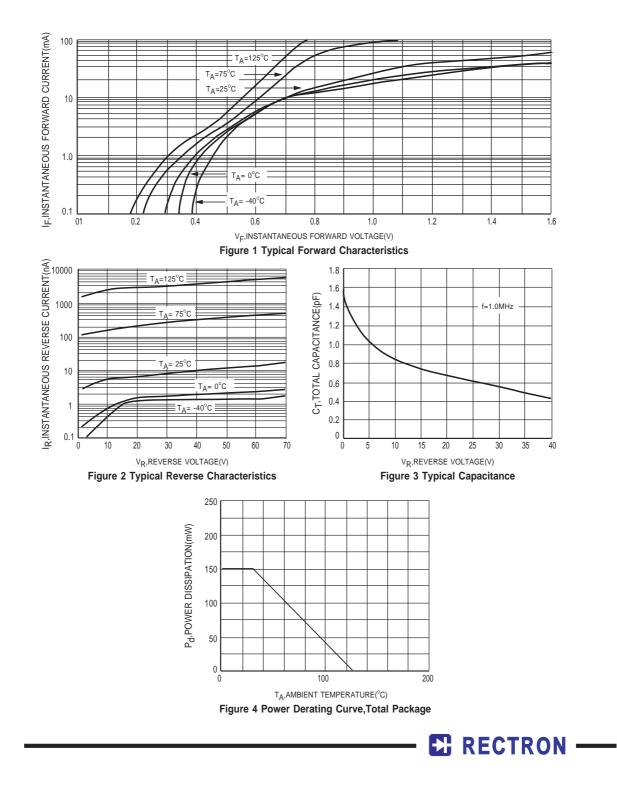
SOT-23 SCHOTTKY DIODE



CHARACTERISTICS	SYMBOL	MIN.	TYP.	MAX.	UNITS
Reverse breakdown voltage (I _R =10µA)	V _{(BR)R}	70	-	-	V
Reverse voltage leakage current (V _R =50V)	I _R	-	-	100	nA
Forward voltage (I _F =1mA)	VF	-	-	410	mV
(I _F =15mA)				1000	
Diode capacitance (V _R =0,f=1MHz)	CD	-	-	2	pF
Reveres recovery time (I_F=I_R=10mA,I_{TT}=0.1 X I_R, R_L=100\Omega	t _{rr}	-	-	5	nS

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